WATERTOWN DIVISION

## Silicon Switching Diode

Product Preview

## DESGRIPTION

These silicon switching diodes are available in DO- 35 glass packages and LL4938 Mini-Melf (DO-213AA).

These devices are used in generalpurpose applications where high voltage and switching speed are important.

IMPORTANT: For the mostcurent data, consultMICROSEMP's website: http://www.microsemi.com

| ABSOLUTE MAXIMUM RATINGS AT $25^{\circ} \mathrm{C}$ <br> (UNLESS OTHERWISE SPECIFIED) |  |  |  |
| :---: | :---: | :---: | :---: |
| Rating | Symbol | Value | Unit |
| Peak Inverse Voltage@ 100 $\mathrm{A}^{\text {A }}$ | PIV | 200(Min.) | Volts |
| Average Rectified Current | $\mathrm{I}_{\text {A vg }}$ | 100 | mAmps |
| Continuous Forward Current | $\mathrm{I}_{\mathrm{F} \text { dc }}$ | 100 | mAmps |
| Peak Surge Current ( $\mathrm{t}_{\text {peak }}=1 \mu \mathrm{sec}$.) | $\mathrm{I}_{\text {peak }}$ | 1.0 | Amp |
| Power Dissipation $\mathrm{T}_{\mathrm{L}}=50^{\circ} \mathrm{C}$, $L=3 / 8^{\prime \prime}$ from body | $\mathrm{P}_{\text {tot }}$ | 500 | mWatts |
| Storage Temperature Range | Tst | -65 to +200 | ${ }^{\circ} \mathrm{C}$ |
| Operating Temperature | Top | -65 to +175 | ${ }^{\circ} \mathrm{C}$ |

When ordering Mil-PRF-19500/169 parts, use the number with the appropriate 1N4938-1 JAN, JTX or JTXV prefix.

- APPLICATIONS/BENEFITS
- High Voltage and Switching Speed.
- metallurgical bonded.
- available up to JANTXV for 1N4938-1 axial devices \& 1N4938UR-1 MINI-MELF.


1N4938

## KEY FEATURES

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| Parameter | Symbol | Conditions | Min | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Forward Voltage Drop | $\mathrm{V}_{\mathrm{F}}$ | $1_{F}=100 \mathrm{~mA}$ |  | 1.0 | V |
| Reverse Leakage Current @150ํ. | IR | $\mathrm{V}_{\mathrm{R}}=175 \mathrm{~V}$ |  | 100 | $\mu \mathrm{A}$ |
| Reverse Leakage Current | $\mathrm{I}_{\mathrm{R}}$ | $\mathrm{V}_{\mathrm{R}}=175 \mathrm{~V}$ |  | 100 | nA |
| Capacitance | $\mathrm{C}_{\text {T }}$ | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{~F}=1 \mathrm{MHz}$ |  | 5.0 | PF |
| Reverse Recovery Time | Trr | (See note 1) |  | 50 | ns |

Note 1: Per Method 4031-B with $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{R}}=30 \mathrm{ma}, \mathrm{R}_{\mathrm{L}}=100 \mathrm{Ohms}, \mathrm{C}=3 \mathrm{Pf}$

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1N4938 DO-35 Glass Package

## (nominal dimensions)



LL4938 LL-34/35 MINI-MELF
SMD Package (DO-213AA)
(nominal dimensions)

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Product Preview

